NSN 5961-01-014-4027

Yes - demil/mli

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Photo Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-014-4027 **Inclosure Material:** Metal **Overall Length:** 0.365 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 1.020 inches **Function For Which Designed:** Photodiode **Internal Configuration:** Junction contact **Mounting Method: Terminal Criticality Code Justification: Semiconductor Material:** Silicon **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Weapon system essential; protective dust cap; internal junction configuration; pin **Precious Material And Location:** Plated case gold **Precious Material:** Gold **Test Data Document:** 98752-9916370 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 6 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:**